

100V HIGH VOLTAGE PNP SURFACE MOUNT TRANSISTOR
Features

- Epitaxial Planar Die Construction
- High Collector-Emitter Voltage $BV_{CEO} > -100V$
- Ideally Suited for Automated Assembly Processes
- Ideal for Power Switching or Amplification Applications
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

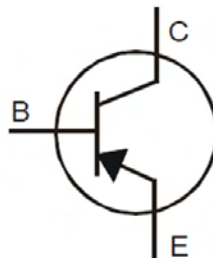
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.34 grams (approximate)

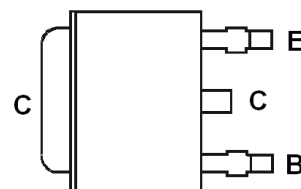
TO252 (DPAK)



Top View



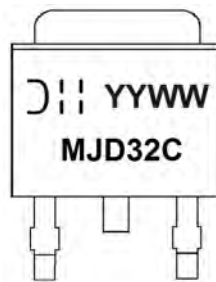
Device Schematic


 Pin Out Configuration
Top view

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MJD32C-13	AEC-Q101	MJD32C	13	16	2,500
MJD32CQ-13	Automotive	MJD32C	13	16	2,500

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information


MJD32C = Product Type Marking Code
 DII = Manufacturers' code marking
 YYWW = Date Code Marking
 YY = Last Digit of Year (ex: 10 = 2010)
 WW = Week Code (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

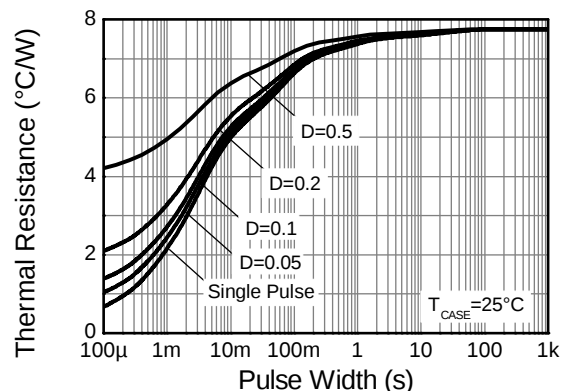
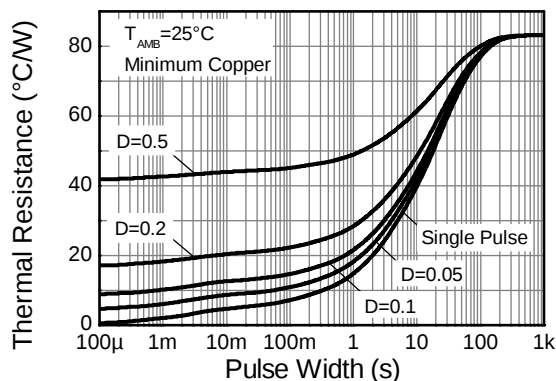
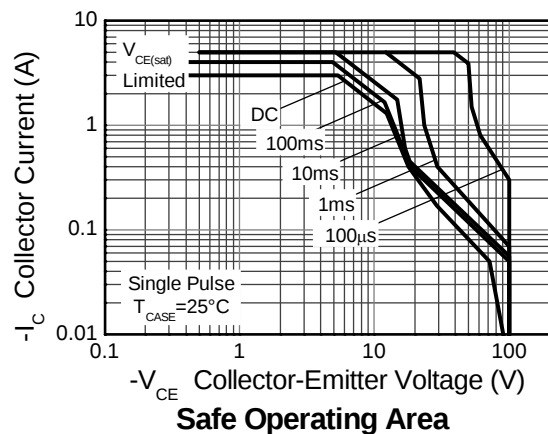
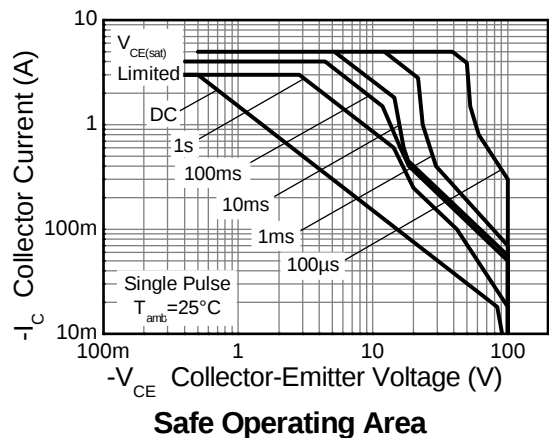
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-100	V
Collector-Emitter Voltage	V _{CE0}	-100	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	I _C	-3	A
Peak Pulse Collector Current	I _{CM}	-5	A
Continuous Base Current	I _B	-1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	1.56	W
Power Dissipation (Note 7)	P _D	15	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	80	°C/W
Thermal Resistance, Junction to Leads (Note 7)	R _{θJL}	8.33	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 6. Device mounted on FR-4 PCB with minimum recommended pad layout.
7. Thermal resistance from junction to solder-point (on the exposed collector pad).

Thermal Characteristics



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-100	—	—	V	I _C = -30mA, I _B = 0
Collector Cut-off Current	I _{CEO}	—	—	-1	μA	V _{CB} = -60V, I _B = 0
Collector Cut-off Current	I _{CES}	—	—	-1	μA	V _{CE} = -100V, V _{EB} = 0
Emitter Cut-off Current	I _{EBO}	—	—	-1	μA	V _{EB} = -5V, I _C = 0
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	—	—	-1.2	V	I _C = -3.0A, I _B = -375mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	—	—	-1.8	V	I _C = -3A, V _{CE} = -4V
DC Current Gain (Note 8)	h _{FE}	25 10	—	— 50	—	V _{CE} = -4V, I _C = -1A V _{CE} = -4V, I _C = -3A
Current Signal Current Gain	H _{fe}	20	—	—	—	V _{CE} = -10V, I _C = -0.5A, f = 1KHz
Current Gain-Bandwidth Product	f _T	3.0	—	—	MHz	I _C = -500mA, V _{CE} = -10V, f = 1MHz

Notes: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

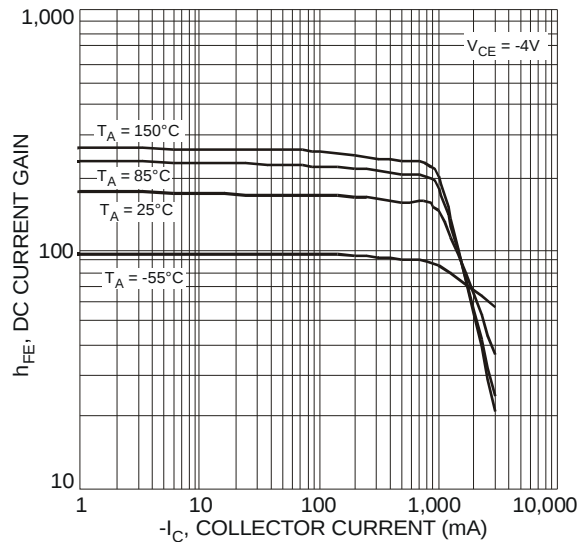


Figure 1 Typical DC Current Gain vs. Collector Current

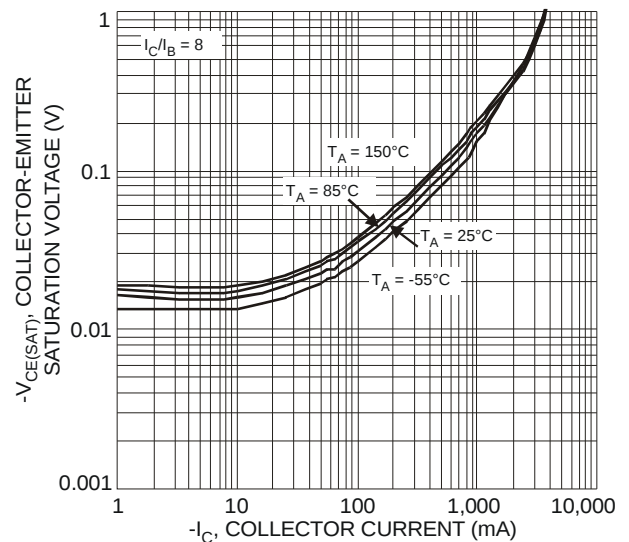


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

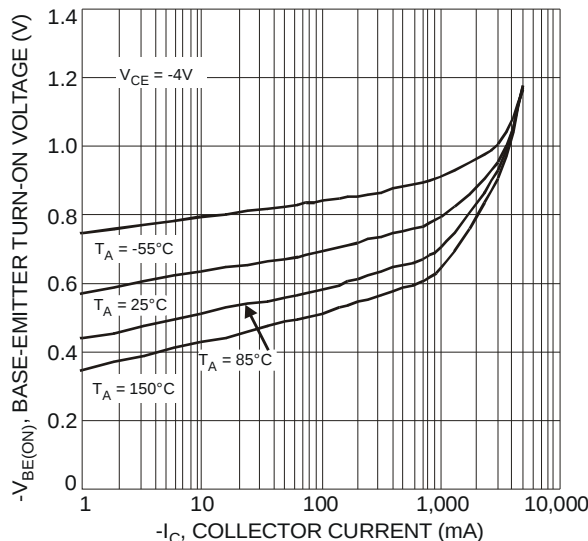


Figure 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

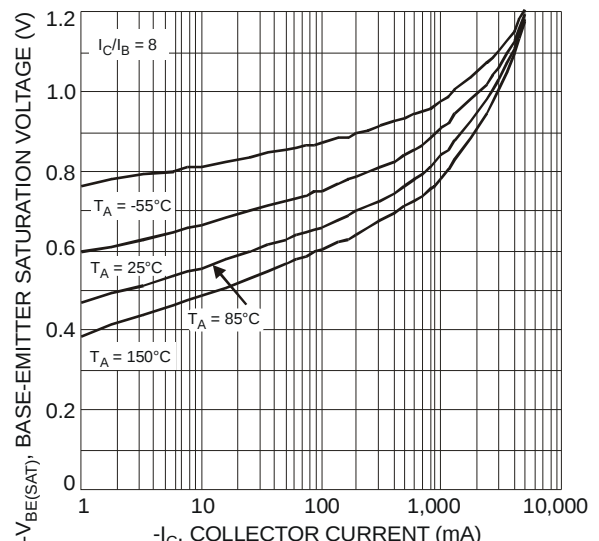
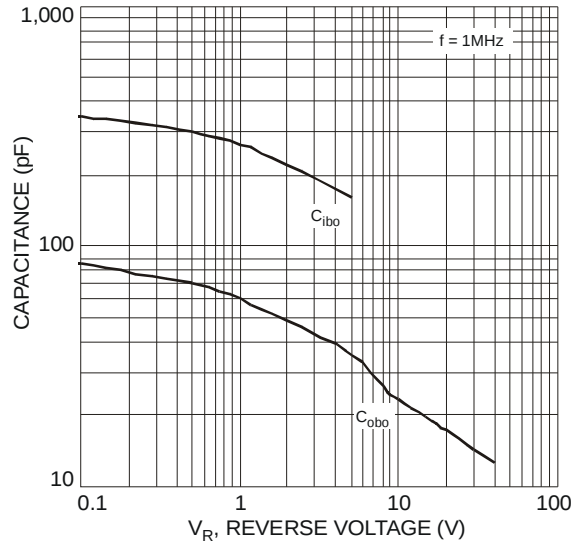
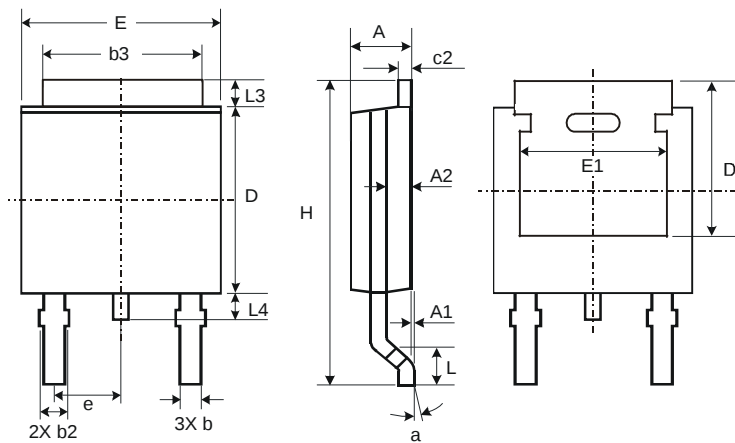


Figure 4 Typical Base-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

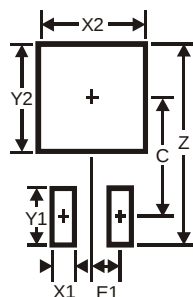
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



TO252			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.46	5.33
c2	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	—	—
e	—	—	2.286
E	6.45	6.70	6.58
E1	4.32	—	—
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
C	6.9
E1	2.3

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9